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Date:

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From:

Joanna G. Chiu- 43,629

Subject:

10/657,593- William C. Moyer

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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	Applicants: Application N Date Filed: Title:	September 8, 2003 DATA PROCESSING SYSTEM HAVI		2183 Unknown SC13075TH CIFIERS FOR SIMC			
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	Commissione P.O. Box 14 Alexandria,	for Patents	,	,			
	attached For	ecordance with 37 C.F.R. §1.56 and in compliant PTO/SB/08 and/or subsequently identified herein and Trademark Office.					
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	a. D b. [c. [are in the English language (concise explana A concise explanation of the relevance of all English language is as follows: The following additional information is provide	this section, all of the pa tion not required). patents, publications or ed for the Examiner's con	other information listed that is not in the			
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The Examiner is advised that the following co-pending application(s) contain(s) subject matter that may be related to the present application. By bringing this (these) applications to the Examiner's attention, Applicant(s) does(do) not

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waive the confidentiality provisions of 35 U.S.C. §122.

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a	within three months of the filing date of a national application other than a continued prosecution application under § 1.53(d) (37 C.F.R. §1.97(b)(1)). No fee or statement is required. within three months of the date of entry of the national stage as set forth in § 1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement is required. before the mailing date of a first Office Action on the merits (37 C.F.R. §1.97(b)(3)). No fee or statement is required. before the mailing date of a first Office Action after the filing of a request for continued examination under § 1.114 (37 C.F.R. § 1.97(b)(4)). No fee or statement is required.
c.⊠ d.□	within three months of the date of entry of the national stage as set forth in § 1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement is required. before the mailing date of a first Office Action on the merits (37 C.F.R. §1.97(b)(3)). No fee or statement is required. before the mailing date of a first Office Action after the filing of a request for continued examination under §
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	before the mailing date of a first Office Action after the filing of a request for continued examination under §
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	a. D b. D on or be 1) 2) STATEM The und a. D c. D

The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in a combination, to a person of ordinary skill in the art.

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If the Examiner has any questions concerning this IDS, he/she is requested to contact the undersigned. If it is determined that this IDS has been filled under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 503079, Freescale Semiconductor, Inc.

Respectfully submitted, William C. Moyer

FREESCALE SEMICONDUCTOR, INC. Customer Number 23125

Enclosures:

PTO/SB/08 References

Other:

Jeanna G. Chiu Attorney for Applicant(s) Reg. No. 43,629

Tel. 512-996-3839

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Substitute for form 1449A/PTO		Complete if Known	_
	Application Number	10/657,593	
INFORMATION DISCLOSURE	Filing Date	September 8, 2003	
STATEMENT BY APPLICANT	First Named Inventor	William C. Moyer	
	Group Art Unit	2183	
(use as many sheets as necessary)	Examiner Name	Unknown	
Sheet 1 of 1	Attorney Docket Number	\$G13075TH	

	1			U. S. PATENT DOCUMENTS		
Examiner Initials*	Gile No.		cument nd Code ² f known)	Name of Palontae or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Linos, Where Relevan Passages or Relevant Figures Appear
•	EA	6,647,546	B1	Hinker et al.	11-11-2003	
	EB	6,513,107	B1	Ansari	01-28-2003	
	EC	6,381,687	B2	Sandstrom st al.	04-30-2002	
	ED	5,390,352		Kinoshita	02-14-1995	
	EE	2004/0117595	A1	Norris et al.	06-17-2004	
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